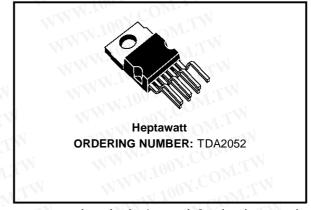


TDA2052

60W Hi-Fi AUDIO POWER AMPLIFIER WITH MUTE / STAND-BY

- SUPPLY VOLTAGE RANGE UP TO ±25V
- SPLIT SUPPLY OPERATION
- HIGH OUTPUT POWER (UP TO 60W MUSIC POWER)
- LOW DISTORTION
- MUTE/STAND-BY FUNCTION
- NO SWITCH ON/OFF NOISE
- AC SHORT CIRCUIT PROTECTION
- THERMAL SHUTDOWN
- ESD PROTECTION



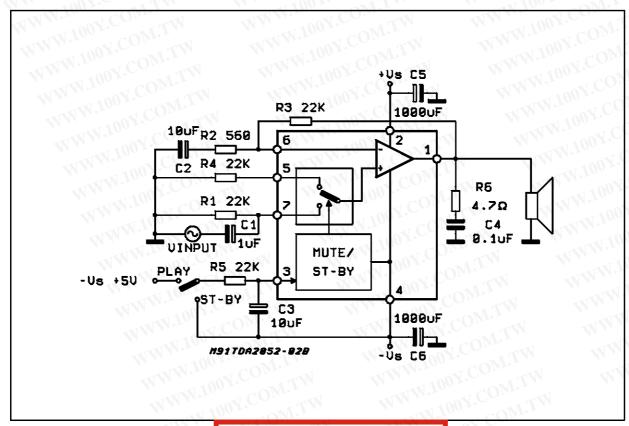
DESCRIPTION

The TDA2052 is a monolithic integrated circuit in Heptawatt package, intended for use as audio class AB amplifier in TV or Hi-Fi field application. Thanks to the wide voltage range and to the high out current capability it's able to supply the high-

est power into both 4Ω and 8Ω loads even in presence of poor supply regulation.

The built in Muting/Stand-by function simplifies the remote operations avoiding also switching on-off noises.

TEST AND APPLICATION CIRCUIT

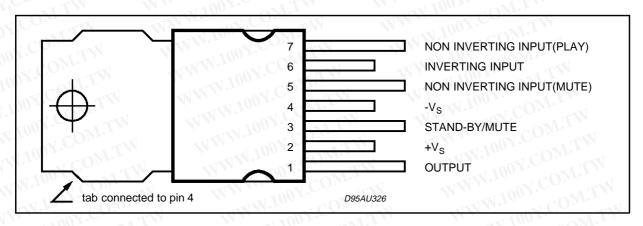


February 1997

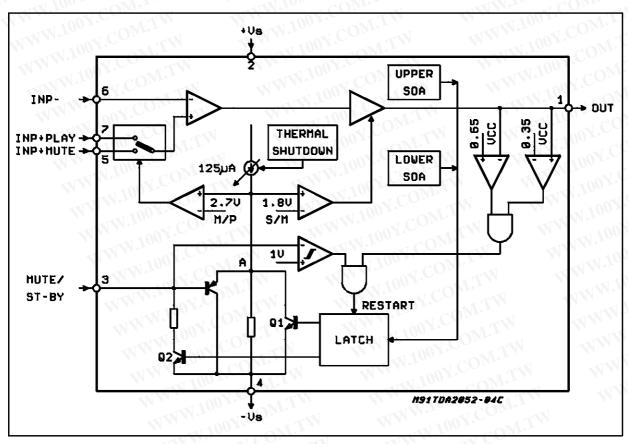
ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit	
Vs	DC Supply Voltage	±25	V	
lo	Output Peak Current (internally limited)	CO _M 6	А	
P _{tot}	Power Dissipation T _{case} = 70°C	30	W	
T_{op}	Operating Temperature Range	0 to +70	°C	
T_{stg}, T_{j}	Storage and Junction Temperature	-40 to +150	°C	

PIN CONNECTION (Top view)



BLOCK DIAGRAM



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THERMAL DATA

Symbol	Description	1	Value	Unit
R _{th j-case}	Thermal Resistance Junction-case	Max	2.5	°C/W

ELECTRICAL CHARACTERISTICS (Refer to the test circuit, G_V = 32dB; V_S ± 18V; f = 1KHz; T_{amb} = 25°C, unless otherwise specified.)

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
V_S	Supply Range	TN WW.	<u>+</u> 6	TIM	<u>+</u> 25	V
ONIq	Total Quiescent Current	V _S = <u>+</u> 22V	20	40	√ 70	mA
I_b	Input Bias Current	W. T.	To	O_{Mr}	<u>+</u> 0.5	μΑ
Vos	Input Offset Voltage	W.I.	1.700 7.	Mor	<u>+</u> 15	mV
Ios	Input Offset Current	WW.	1007		<u>+</u> 200	nA
Po	Music Output Power IEC268-3 Rules (*)	$V_S = \pm 22.5, R_L = 4\Omega,$ d = 10%, t = 1s	50	60	NT.1	W
Po Po	Output Power (continuous RMS)	$d = 10\%$ $RL = 4\Omega$ $R_L = 8\Omega$ $V_S = \pm 22V, R_L = 8\Omega$	35 30	40 22 33	M.TV	W W W
100 X C	OW.TW WWW.I	$\begin{aligned} &d=1\%\\ &R_L=4\Omega\\ &R_L=8\Omega\\ &V_S=\pm 22V,R_L=8\Omega \end{aligned}$	WWW.	32 17 28	COM:	>
M. q	Total Harmonic Distortion	$R_L = 4\Omega$ $P_O = 0.1 \text{ to } 20\text{W};$ f = 100Hz to 15KHz	MM	0.1	0.7	%
MM.10	N.COM.TW WY	$V_S \pm 22V$, $R_L = 8\Omega$ $P_O = 0.1$ to 20W; f = 100Hz to 15KHz	W	0.1	0.5	0M⋅ %
SR	Slew Rate	MM.In. COM.	3	5	, Vo	V/µs
G_V	Open Loop Voltage Gain	M.100 - COW.1	- T	80	1700	dB
e _N	Total Input Noise	A Curve f = 20Hz to 20KHz		2 3	10	μV μV
R_i	Input Resistance	M.100 - COW.	500		M.In.	ΚΩ
SVR	Supply Voltage Rejection	f = 100Hz, Vripple = 1VRMS	40	50	XX 10	dB
Ts	Thermal Shutdown	MAN W.	TO VI	145	Mar.	~°C

MUTE/STAND-BY FUNCTION (Ref. -Vs)

VT _{ST-BY}	Stand-by - Threshold	M.M. O. CO.	1	1.8	MAN	V
VT_{PLAY}	Play Threshold	WW.Inc COL	1. *	2.7	4	V
I _{q ST-BY}	Quiescent Current @ Stand-by	$V_{pin 3} = 0.5V$	M.T.	1	3	mA
ATT _{ST-BY}	Stand-by Attenuation	WW. 100X.Co	70	90	11/1/	dB
I _{pin3}	Pin 3 Current @ Stand-by	WWW.	DIA.	√\-1	<u>+</u> 10	μΑ

Note (*):

MUSIC POWER CONCEPT

MUSIC POWER is (according to the IEC clauses n.268-3 of Jan 83) the maximal power which the amplifier is capable of producing across the rated load resistance (regardless of non linearity) 1 sec after the application of a sinusoidal input signal of frequency 1KHz.

According to this definition our method of measurement comprises the following steps:

- 1) Set the voltage supply at the maximum operating value -10%
- 2) Apply a input signal in the form of a 1KHz tone burst of 1 sec duration; the repetition period of the signal pulses is > 60 sec
- 3) The output voltage is measured 1 sec from the start of the pulse
- 4) Increase the input voltage until the output signal show a THD = 10%
 5) The music power is then V²_{out}/R1, where V_{out} is the output voltage measured in the condition of point 4) and R1 is the rated load impedance

The target of this method is to avoid excessive dissipation in the amplifier.



APPLICATIONS SUGGESTIONS (See Test and Application Circuit)

The recommended values of the external components are those shown on the application circuit. Different values can be used; the following table can help the designer.

Comp.	Value	Purpose	Larger Than	Smaller Than
R1	22KΩ (*)	Input Impedance	Increase of Input Impedance	Decrease of Input Impedance
R2	560Ω	Closed Loop Gain set to	Decrease of Gain	Increase of Gain
R3	22KΩ (*)	32dB (**)	Increase of Gain	Decrease of Gain
R4	22KΩ (*)	Input Impedance @ Mute	TWW.In	OM
R5	22ΚΩ	Stand-by Time Constant	W. 1001.	COM:
R6	4.7Ω	Frequency Stability	Danger of oscillations	Danger of oscillations
OC1	1μF	Input DC Decoupling	WWW.100	Higher Low-frequency cut-off
C2	10μF	Feedback DC Decoupling	MW.10	Higher Low-frequency cut-off
C3	10μF	Stand-by Time Constant	1.11	Mr. COM:
C4	0.100μF	Frequency Stability	M. MM.	Danger of Oscillations
C5, C6	1000μF	Supply Voltage Bypass	THIN.	ON COM

^(*) R1 = R3 = R4 for POP optimization

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TYPICAL CHARACTERISTICS

Figure 1: Output Power vs. Supply Voltage

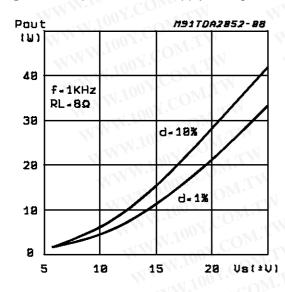
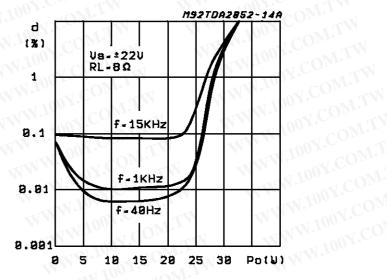


Figure 2: Distortion vs. Output Power



^(**) Closed Loop Gain has to be ≥ 30dB

Figure 3: Output Power vs. Supply Voltage.

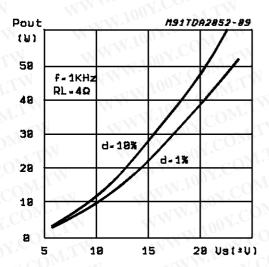


Figure 5: Distortion vs. Frequency.

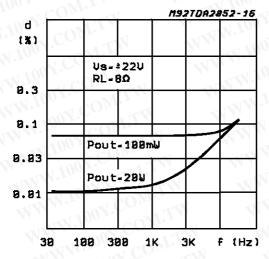


Figure 7: Quiescent Current vs. Supply Voltage

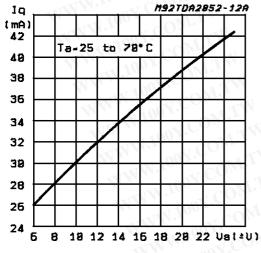


Figure 4: Distortion vs. Output Power.

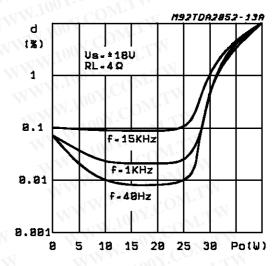


Figure 6: Distortion vs. Frequency.

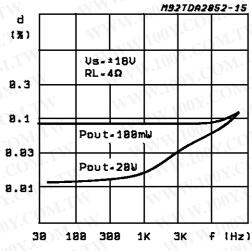


Figure 8: Supply Voltage Rejection vs. Frequency.

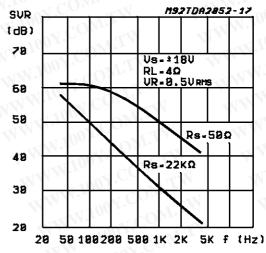


Figure 9: Bandwidth.

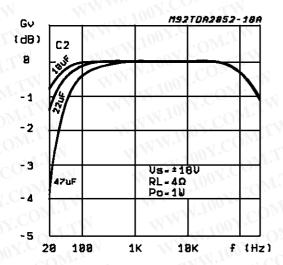


Figure 10: Output Attenuation & Quiescent Cur-

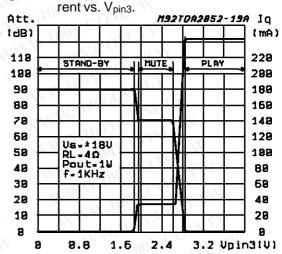


Figure 11: Total Power Dissipation & Efficiency vs. Output Power.

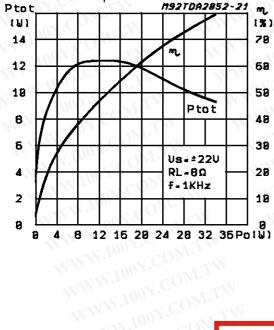
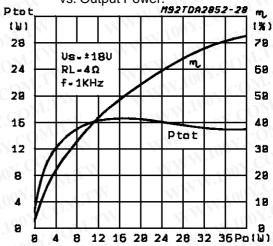


Figure 12: Total Power Dissipation & Efficiency vs. Output Power.



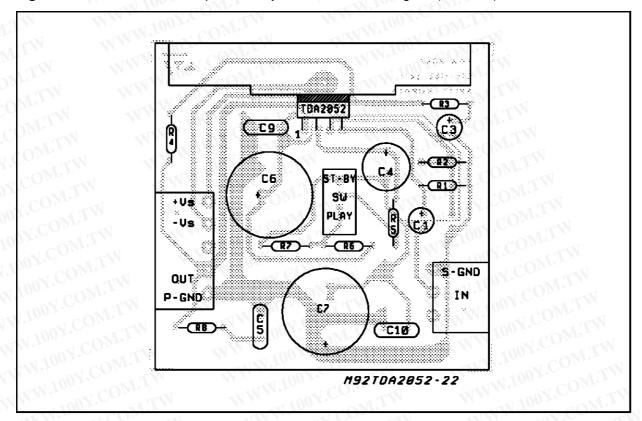
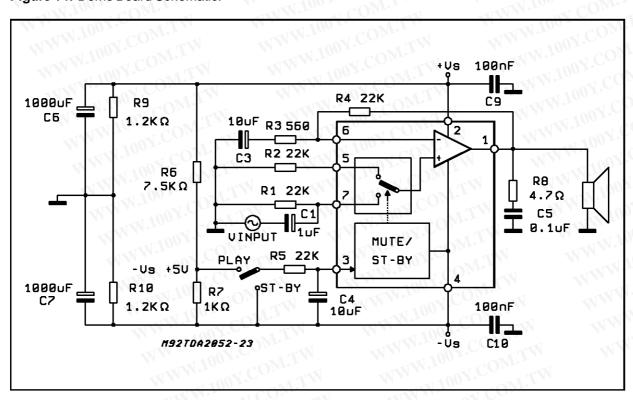


Figure 13: P.C. Board and Components Layout of the Circuit of Fig. 14 (1:1 scale)

Figure 14: Demo Board Schematic.



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MUTE/STAND-BY FUNCTION

The pin 3 (MUTE/STAND-BY) controls the amplifier status by three different thresholds, referred to-Vs.

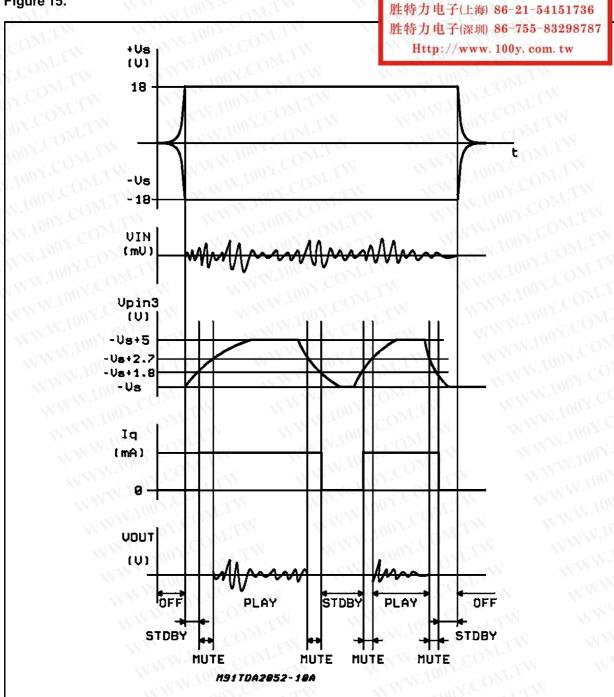
When its voltage is lower than the first threshold (1V, with a ±70mV hysteresis), the amplifier is in STAND-BY and all the final stage current generators are off. Only the input MUTE stage is on in order to prevent pop-on problems.

At V_{pin3}=1.8V the final stage current generators are switched on and the amplifier operates in MUTE.

For V_{pin3} =2.7V the amplifier is definitely on (PLAY condition)

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SHORT-CIRCUIT PROTECTION

The TDA 2052 has an original circuit which protects the device during accidental short-circuit between output and GND / -Vs / +Vs, taking it in STAND-BY mode, so limiting also dangerous DC current flowing throught the loudspeaker.

If a short-circuit or an overload dangerous for the final transistors are detected, the concerned SOA circuit sends out a signal to the latching circuit (with a 10 μ s delay time that prevents fast random spikes from inadvertently shutting the amplifier off) which makes Q₁ and Q₂ saturate (see Block Diagram). Q₁ immediately short-circuits to ground the A point turning the final stage off while Q₂ short-circuits to ground the external capacitor driving the pin 3 (Mute/Stand-by) towards zero potential.

Only when the pin 3 voltage becomes lower than 1V, the latching circuit is allowed to reset itself and restart the amplifier, provided that the short-circuit condition has been removed. In fact, a window comparator is present at the output and it is aimed at preventing the amplifier from restarting if the output voltage is lower than 0.35 Total Supply Voltage or higher than 0.65 Total Supply Voltage. If the output voltage lies between these two thresholds, one may reasonably suppose the short-circuit has been removed and the amplifier may start operating again.

The PLAY/MUTE/STAND-BY function pin (pin 3) is both ground- and positive supply-compatible and can be interfaced by means of the R_5 , C_3 net either to a TTL or CMOS output (μ -Processor) or to a specific application circuit.

The R₅, C₃ net is fundamental, because connecting this pin directly to a low output impedance driver such as TTL gate would prevent the correct operation during a short-circuit. Actually a final stage overload turns on the protection latching circuit that makes Q₂ try to drive the pin 3 voltage under 0.8 V. Since the maximum current this pin can stand is 3 mA, one must make sure the following condition is met:

$$R_5 \ge \frac{(V_A - 0.7V)}{3mA}$$

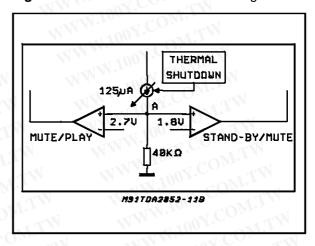
that yields: $R_{5, min} = 1.5 \text{ K}\Omega$ with $V_A = 5V$.

In order to prevent pop-on and -off transients, it is advisable to calculate the C_3 , R_5 net in such a way that the STAND-BY/MUTE and MUTE/PLAY threshold crossing slope (positive at the turn-on and vice-versa) is less than 100 V/sec.

THERMAL PROTECTION

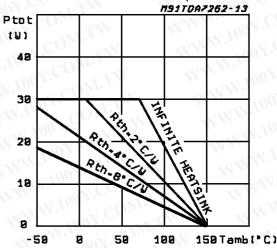
The thermal protection operates on the $125\mu A$ current generator, linearly decreasing its value from 90°C on. By doing this, the A voltage slowly decreases thus switching the amplifier first to MUTE (at $145^{\circ}C$) and then to STAND-BY $(155^{\circ}C)$.

Figure 16: Thermal Protection Block Diagram



The maximum allowable power dissipation depends on the size of the external heatsink (thermal resistance case-ambient); figure 17 shows the dissipable power as a function of ambient temperature for different thermal resistance.

Figure 17: Maximum Allowable Power Dissipation vs. Ambient Temperature.



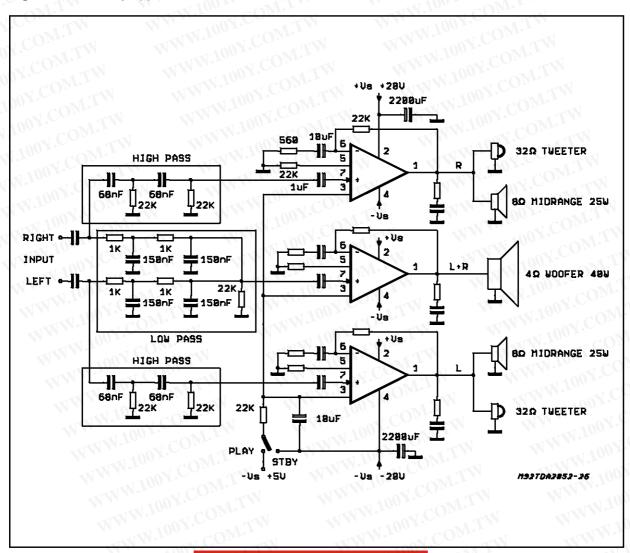
APPLICATION NOTES 90W MULTIWAY SPEAKER SYSTEM

The schematic diagram of figure 18, shows the solution that we have closen as a suggestion for Hi-Fi and especially TV applications.

The multiway system provides the separation of the musical signal not only for the loudspeakers, but also for the power amplifiers with the following advantages:

- reduced power level required of each individual amplifier
- complete separation of the ways (if an amplifier is affected by clipping distortion, the others are not)
- protection of tweeters (the high power harmonics generated by low frequency clipping can not damage the delicate tweeters that are driven by independent power amplifier)
- high power dedicated to low frequencies

Figure 18: Multiway Application Circuit



As shown in Figure 19, the R-C passive network for low-pass and High-pass give a cut with a slope of 12dB/octave

A further advantage of this application is that connecting each speaker directy to its amplifier, the musical signal is not modified by the variations of the impedance of the crossover over frequency.

The subwoofer is designed for obtaining high sound pressure level with low distortion without stereo effect.

In the application of figure 18, the subwoofer plays the 20 to 300 Hz frequency range, while the remaining 300 Hz to 20KHz are sent to two separate channels with stereo effect.

The multiway system makes use of three TDA2052, one for driving the subwoofer with Pout higher than 40W (THD = 10%), 28W undistorted (THD = 0.01%), while the others two TDA2052 are used for driving the mid/high frequency speakers of L/R channels, delivering Pout = 25W (THD = 10%) and 20W @ THD = 0.01%

Figure 20: Distortion vs Output Power (Subwoofer)

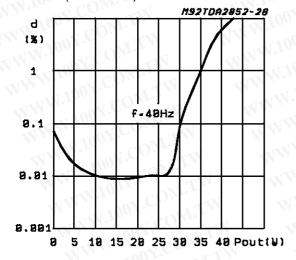


Figure 19: Frequency Response

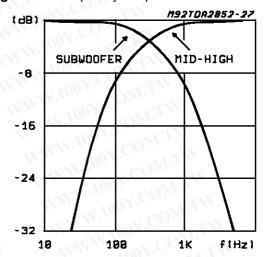
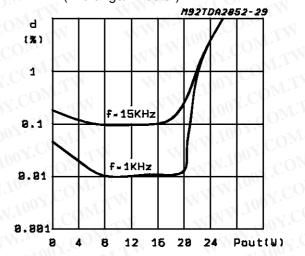


Figure 21: Distortion vs Output Power (Midrange/Tweeter)



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HEPTAWATT PACKAGE MECHANICAL DATA

DIM.	Y WY LOOK	mm			inch		
	MIN.	CO TYP.	MAX.	MIN.	TYP.	MAX	
Α	. Tan M. Ino	COM	4.8	N. In C	DIAT.	0.189	
С	W '' 100	J. OWITA	1.37	1W.100	OM:	0.054	
D	2.4	OY.CO	2.8	0.094	M.T.W	0.110	
D1	1.2	ON COM	1.35	0.047	TW	0.053	
E	0.35	ing -1 COM.	0.55	0.014	COMP	0.022	
F	0.6	100 J.	0.8	0.024	COMIT	0.031	
F1	MW	1007.00	0.9	WW. 10	TMI	0.035	
G	2.41	2.54	2.67	0.095	0.100	0.105	
G1	4.91	5.08	5.21	0.193	0.200	0.205	
G2	7.49	7.62	7.8	0.295	0.300	0.307	
H2		1007.0	10.4	MAL	1007.	0.409	
H3	10.05	WW.	10.4	0.396	TOUX.CO.	0.409	
LOM		16.97	COM	TIW.	0.668	T.	
L1	V LA	14.92	OMIT		0.587	M.I	
L2	WT	21.54	Y. TI		0.848	MILMO	
L3		22.62	N.COM	W W	0.891		
1 L5	2.6	W.IV	3	0.102	WW.I	0.118	
L6	15.1	W Tan J	15.8	0.594	W.100 E	0.622	
L7	6	MW.	6.6	0.236	N 1 1003	0.260	
M	COM	2.8	, OA.COL	W	0.110	Y.Co.	
M1	COM.	5.08	1.100 TCO	Mr.	0.200	ov.CON	
Dia	3.65		3.85	0.144	11.10	0.152	

